# NSN 5961-01-495-2524

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## Inclosure Material:

Metal

# Overall Length:

Between 1.250 inches and 1.500 inches

# **Overall Height:**

Between 1.540 inches and 1.552 inches

## **Overall Width:**

Between 1.250 inches and 1.500 inches

#### **Overall Diameter:**

Between 0.846 inches and 1.847 inches

#### **End Application:**

Arc-190 and arc-230 hr radio's

## Internal Configuration:

Junction contact

#### Mounting Method:

Press fit

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

110.0 breakdown voltage, collector-to-base, emitter open and 110.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 3.6 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

22.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

320.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

010) shall consist of two matchedpairs having the same alpha designator of rf gain; junction pattern arrangement: npn

#### Terminal Type And Quantity:

4 ribbon

#### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

# Fiig:

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